

2016

PHYSICS

PAPER : PHY 203

ELECTRONICS

(Old Course)

Full Mark : 80

Time : 3 Hrs

Figures in the right hand margin indicate full marks for the question

1. Answer any five questions: 2 × 5 = 10
- (a) Plot the following Boolean function on a three variable K-map.
- $$Y = f^om(1,3,5,6)$$
- (b) Write an expression for frequency stability of phase shift oscillator. What is the total phase of this oscillator?
- (c) What are the minimum number of gates generally incorporated in fabricating the LSI and VSLI?
- (d) State the role of oxide layer of E-MOSFET
- (e) Give the two basic differences between general diode and tunnel diode?
- (f) The rms antenna current of an AM radio transmitter is

10A when unmodulated and 12A when sinusoidally modulated. What is modulation index?

2. Answer any four questions: $5 \times 4 = 20$

- (a) Discuss with band diagram how negative resistance of Tunnel Diode can be obtained.
- (b) (i) A carrier wave of 12V is modulated by a modulating signal of amplitude 6V. Find the ratio P_t/P_c .
(ii) Draw the field profiles for TE_{10} mode in a rectangular wave guide.
- (c) Discuss with band diagram how negative resistance of Tunnel diode may be obtained? Explain with necessary expressions under what conditions the Tunnel diode circuit becomes (a) non-oscillatory and (b) sinusoidal.
- (d) What is roll off rate of a 1st order filter? Design a second order Butterworth low pass filter having cut-off frequency 1.5 kHz.
- (e) Using OP-AMP, design a circuit to solve the following equations:

$$\frac{d^2y}{dx^2} + 2\frac{dy}{dx} - y = 3$$

with its initial conditions: $y(0)=2$ and $\frac{dy}{dx}\Big|_{t=0} = -1$

- (f) What is characteristic impedance of a transmission line?

(2)

P.T.O.

Show that for a low loss RF transmission line $Z_0 = \sqrt{L/C}$ where L and C are inductance and capacitance per unit length.

3. Answer any five questions: $10 \times 5 = 50$

- (a) Find the voltage and current at any point in a transmission line considering separately an open-circuited line and a short-circuited line from its solution. Prove that, $Z = \sqrt{(Z_{sc} \times Z_{oc})}$, where Z_{sc} and Z_{oc} are open circuited and short circuited input impedances. $5+5=10$
- (b) Plot the following Boolean function on K-map and find its reduced function in SOP form. Draw the logic circuit:

$$F = \sum m (0,3,4,5,5,8,10,12) \quad 3+3+4=10$$

- (c) Draw the basic structure of an n-channel E-MOSFET and explain its operation. What is CMOS? Draw an inverter circuit using MOSFET. $2+4+1+3=10$
- (i) A rectangular wave guide has a broad wall dimension of 2.275 cm. Determine whether TE_{10} wave will be propagated and if so, find its guide wave length, phase and group velocities. 5

(3)

P.T.O.

(ii) Establish the following expression for propagation constant of rectangular wave guide (a, and b are dimensions): 5

$$\bar{\gamma} = \sqrt{\left[\frac{(\pi m)^2}{a^2} + \frac{(\pi n)^2}{b^2} \right]}$$

(d) (i) What is radiation resistance? "Radiation resistance of a $\lambda/4$ dipole is 73Ω ". What do you understand by the above statement? 4

(ii) Describe about the Horn antenna giving the special emphasis on its dimension for optimum power gain. 6

(e) Define the following terms associated with function of a microprocessor:

(i) Assembling language and Machine language

(ii) Accumulator (iii) SP and PC

Give step by step instructions for processing a job in microprocessor, starting from functioning of I/O port address bus and data bus. 2+2+2+4=10

(f) (i) What is single side band (SSB) modulation and why it is important? Draw a simple circuit of Balance Modulator to separate two side bands. 6

(ii) Draw a block diagram of basic stages in generation of PCM. 4